



Product Summary

V _{(BR)DSS}	Rds(on)	Ι _D T _A = +25°C
100V	4.2Ω @ V _{GS} = -10V	-0.27A
100 v	$5.0Ω @ V_{GS} = -4.0V$	-0.24A

Description

This new generation MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

- DC-DC Converters
- Power Management Functions
- Battery Operated Systems and Solid-State Relays
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.





Top View

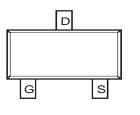
100V P-CHANNEL ENHANCEMENT MODE MOSFET

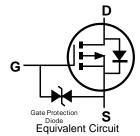
Features and Benefits

- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Small Surface Mount Package
- ESD Protected
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.008 grams (Approximate)





Top View Pin Configuration

Ordering Information (Note 4)

Part Number	Case	Packaging
DMP10H4D2S-7	SOT23	3,000/Tape & Reel
DMP10H4D2S-13	SOT23	10,000/Tape & Reel

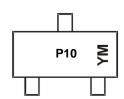
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com.

Marking Information



P10 = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: C = 2015) M = Month (ex: 9 = September)

Date Code Key

Year	2015		2016	2017		2018	2019		2020	2021		2022
Code	С		D	E		F	G		Н	I		J
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Drain-Source Voltage	V _{DSS}	-100	V	
Gate-Source Voltage		V _{GSS}	±20	V
Continuous Drain Current (Note 6) V _{GS} = -10V	ID	-0.27 -0.21	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle ≤1%)	I _{DM}	-1.0	А	
Maximum Body Diode Continuous Current (Note 6)	ls	-0.42	А	

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units			
Total Power Dissipation		(Note 5)	D	0.38	W	
		(Note 6)	PD	0.44	vv	
Thermal Resistance, Junction to Ambient	mal Resistance, Junction to Ambient Steady		R _{0JA}	333		
Thermal Resistance, Junction to Ambient State		(Note 6)	R _{0JA}	282	°C/W	
Thermal Resistance, Junction to Case	(Note 6)	R _{θJC}	115			
Operating and Storage Temperature Range			T _{J,} T _{STG}	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)		-		-	-		
Drain-Source Breakdown Voltage	BV _{DSS}	-100			V	$V_{GS} = 0V, I_D = -250 \mu A$	
Zero Gate Voltage Drain Current	IDSS			1	μA	$V_{DS} = -100V, V_{GS} = 0V$	
Gate-Body Leakage	I _{GSS}		_	±10	μA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	-1.0	-2.3	-3.0	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain-Source On-Resistance	Preven		2.8	4.2	Ω	V _{GS} = -10V, I _D = -0.5A	
	R _{DS(ON)}		3.2	5.0	52	$V_{GS} = -4.0V, I_D = -0.1A$	
Diode Forward Voltage	V _{SD}		-0.82	-1.3	V	$V_{GS} = 0V, I_{S} = -0.2A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss		87			V _{DS} = -25V, V _{GS} = 0V, f = 1.0MHz	
Output Capacitance	Coss		5.6		pF		
Reverse Transfer Capacitance	Crss		2.9				
Gate Resistance	R _G	_	15.3		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge	Qg		1.8				
Gate-Source Charge	Qgs	_	0.3		nC	V _{DS} = -80V, V _{GS} = -10V, I _D = -0.5A	
Gate-Drain Charge	Q _{gd}	_	0.5			$I_{\rm D} = -0.5 A$	
Turn-On Delay Time	t _{D(ON)}	_	3.3	_			
Turn-On Rise Time	t _R	_	2.6		ns	V _{DS} = -50V, I _D = -0.5A,	
Turn-Off Delay Time	t _{D(OFF)}		8.4		115	$V_{GS} = -10V, R_G = 10\Omega$	
Turn-Off Fall Time	tF		4.9				
Reverse Recovery Time	t _{RR}		17.8		ns	V _R = -100V, I _F = -1.0A, di/dt =	
Reverse Recovery Charge	Qrr		24.8		nC	100A/µs	

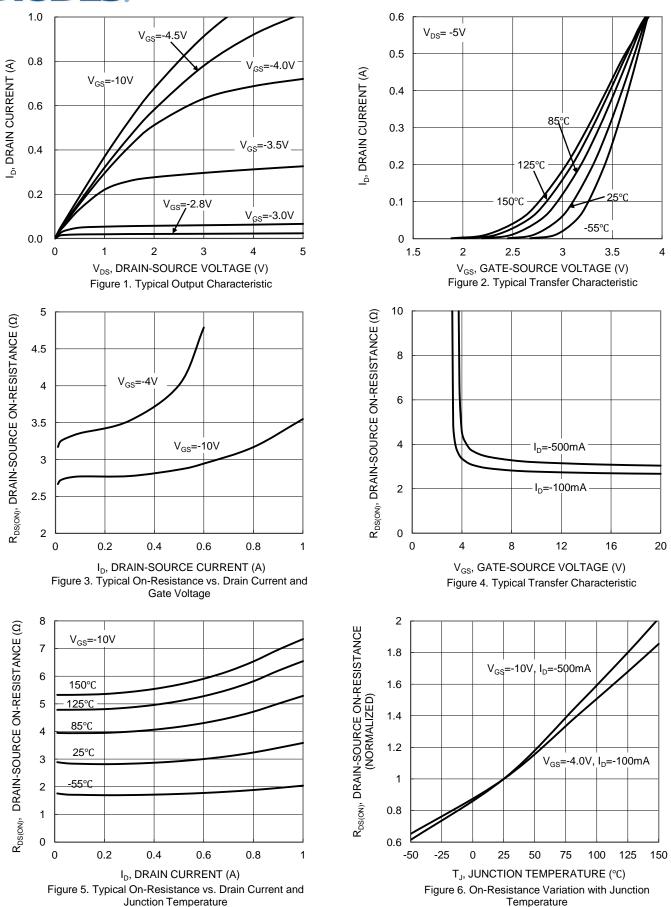
Notes:

5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

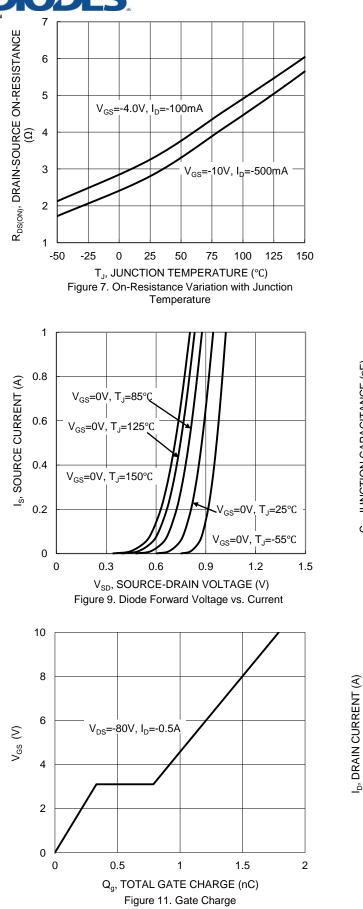
Device mounted on FR-4 substrate PC board, 20z copper, with 1inch square copper pad layout.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to production testing.

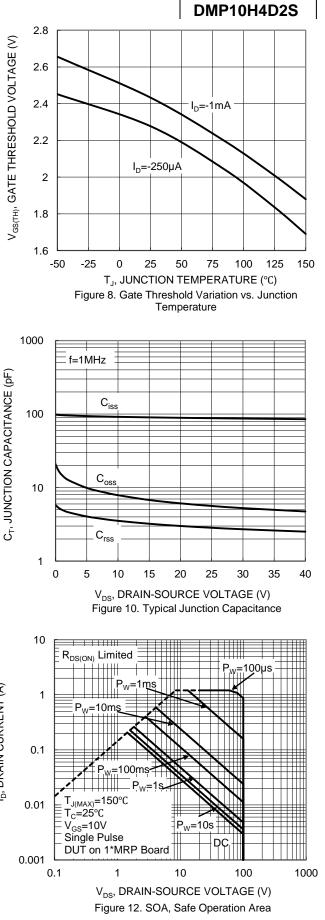


DMP10H4D2S



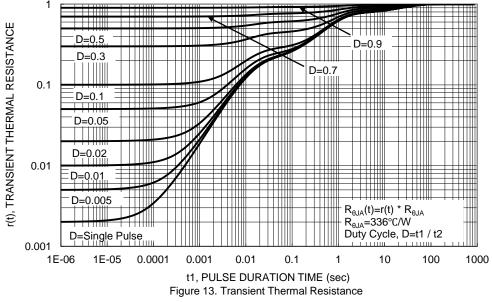






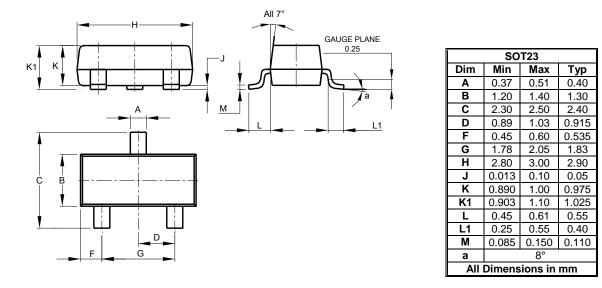


DMP10H4D2S



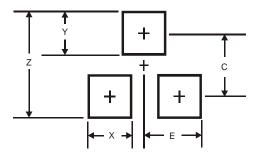
Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimension	Value (in mm)
S	
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35



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